







SN74AHC595-Q1

SCLS537E - AUGUST 2003 - REVISED APRIL 2024

SN74AHC595-Q1 Automotive 8-Bit Shift Register With 3-State Output Registers

1 Features

- Qualified for automotive applications
- Operating range 2V to 5.5V V_{CC}
- 8-bit serial-in, parallel-out shift
- Shift register has direct clear

2 Applications

- Enable or disable a digital signal
- Controlling an indicator LED
- Translation between communication modules and system controllers

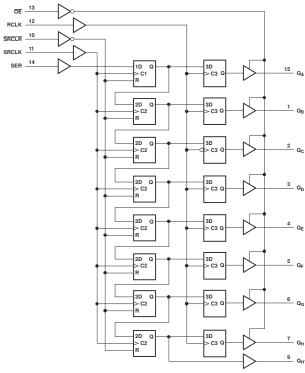
3 Description

The SN74AHC595 contains an 8-bit serial-in, parallelout shift register that feeds an 8-bit D-type storage register.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)
SN74AHC595-Q1	BQB (WQFN, 16)	3.5mm × 2.5mm	3.5mm × 2.5mm
31174A110393-Q1	PW (TSSOP, 16)	5.00mm × 6.40mm	5.00mm × 4.4mm

- For more information, see Section 11. (1)
- (2)The package size (length x width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



Logic Diagram (Positive Logic)

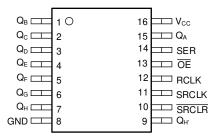


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4 Pin Configuration and Functions



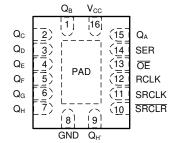


Figure 4-1. PW Package, 16-PIN TSSOP (Top View)

Figure 4-2. BQB Package, 16-Pin WQFN (Top View)

Table 4-1. Pin Functions

Table 4-1. Fill Fullctions							
PIN	TVDE(1)	DESCRIPTION					
NO.	111.	DESCRIPTION					
1	0	Q _B Output					
2	0	Q _C Output					
3	0	Q _D Output					
4	0	Q _E Output					
5	0	Q _F Output					
6	0	Q _G Output					
7	0	Q _H Output					
8	G	Ground Pin					
9	0	Q _H Output					
10	1	SRCLR Input					
11	1	SRCLK Input					
12	1	RCLK Input					
13	I	Output Enable Pin. Active LOW					
14	I	SER Input					
15	0	Q _A Output					
16	Р	Power Pin					
	NO. 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15	NO. TYPE(1) 1 O 2 O 3 O 4 O 5 O 6 O 7 O 8 G 9 O 10 I 11 I 12 I 13 I 14 I 15 O					

⁽¹⁾ I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range	Supply voltage range		7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Output voltage range ⁽²⁾	Output voltage range ⁽²⁾		V _{CC} + 0.5	V
I _{IK}	Input clamp current (V _I < 0)			–20 mA	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20 mA	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±25 mA	mA
	Continuous current through V _{CC} or GND			±75 mA	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

over recommended operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V _{IH}	High-level input voltage	V _{CC} = 3 V	2.1		V
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 2 V		0.5	
V _{IL}	Low-level input voltage	V _{CC} = 3 V		0.9	V
		V _{CC} = 5.5 V		1.65	
VI	Input voltage	,	0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 2 V		-50	μA
I _{OH}	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	Л
		V _{CC} = 5 V ± 0.5 V		-8	mA
		V _{CC} = 2 V		50	μΑ
I _{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	Л
		V _{CC} = 5 V ± 0.5 V		8	mA
A 4 / A	Location of the control of the contr	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	A /
Δt/Δv	t/∆v Input transition rise or fall rate	V _{CC} = 5 V ± 0.5 V		20	ns/V
_		I-suffix devices	-40	85	°C
T _A	Operating free-air temperature	Q-suffix devices	-40	125	C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

5.3 Thermal Information

THERMAL METRIC(1)		BQB (WQFN)	PW (TSSOP)	UNIT
		16 PINS	16 PINS	ONII
$R_{\theta JA}$	Junction-to-ambient thermal resistance	91.8	135.9	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

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⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	TA	= 25°C		MIN MAX	MAY	UNIT
PARAIVIETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	IVIIIN	IVIAA	UNIT
		2 V	1.9	2		1.9		
	$I_{OH} = -50 \mu A$	3 V	2.9	3		2.9		
V _{OH}		4.5 V	4.4	4.5		4.4		V
	I _{OH} = -4 mA	3 V	2.58			2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1	
V _{OL}		4.5 V			0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.44	
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μA
loz	Q_A-Q_H , $V_I = V_{CC}$ or GND, $V_O = V_{CC}$ or GND, $\overline{OE} = V_{IH}$ or V_{IL}	5.5 V			±0.25		±10	μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5 V			4		40	μA
C _i	V _I = V _{CC} or GND	5 V		3	10		10	pF
Co	V _O = V _{CC} or GND	5 V		5.5				pF

5.5 Timing Requirements, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

 V_{CC} = 3.3 V ± 0.3 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	<u>, </u>		T _A = 2	5°C	MIN MA	MAX	UNIT	
			MIN	MAX	IVIIIN	IVIAA	UNIT	
		SRCLK high or low	5.5		6.5			
t _w	t _w Pulse duration	RCLK high or low	5.5		6.5		ns	
		SRCLR low	5		6			
		SER before SRCLK↑	3.5		4.5			
	Setup time	SRCLK↑ before RCLK↑ ⁽¹⁾	8		9.5		20	
t _{su}	Setup time	SRCLR low before RCLK↑	8		10		ns	
		SRCLR high (inactive) before SRCLK↑	3		4			
t _h	Hold time	SER after SRCLK↑	1.5		2.5		ns	

⁽¹⁾ This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

5.6 Timing Requirements, $V_{CC} = 5 V \pm 0.5 V$

 V_{CC} = 5 V ± 0.5 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

			T _A = 2	5°C	MIN	MAY	UNIT
			MIN	MAX	IVIIN	MAX	UNII
	t _w Pulse duration	SRCLK high or low	5		6		
t _w		RCLK high or low	5		6		ns
		SRCLR low	5.2		6.2		

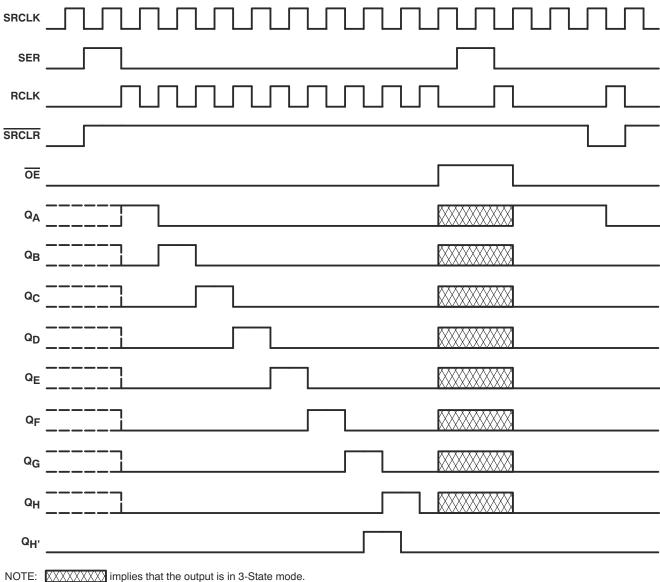


 $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	,		T _A = 2	5°C	MIN	MAX	UNIT
			MIN M 3 5 5	MAX	IVIIIN	IVIAA	UNIT
	SER before SRCLK↑	3		4			
	t _{su} Setup time	SRCLK↑ before RCLK↑ ⁽¹⁾	5		6		
L _{Su}	Setup time	SRCLR low before RCLK↑	5		6		ns
		SRCLR high (inactive) before SRCLK↑	2.5		3.5		
t _h	Hold time	SER after SRCLK↑	2		3		ns

This setup time allows the storage register to receive stable data from the shift register. The clocks can be tied together, in which case the shift register is one clock pulse ahead of the storage register.

5.7 Timing Diagrams



5.8 Switching Characteristics, V_{CC} = 3.3 V ± 0.3 V

 V_{CC} = 3.3 V ± 0.3 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD	TA	= 25°C		MIN	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	IVIIIN	IVIAA	UNII
f _{max}			C _L = 50 pF	55	105		40		MHz
t _{PLH}	RCLK	Q _A –Q _H	$C_1 = 50 \text{ pF}$		7.9	15.4	1	20	ns
t _{PHL}		QA-QH	OL = 30 pr		7.9	15.4	1	20	115
t _{PLH}	SDCI K	SRCLK Q _{II}	C _L = 50 pF		9.2	16.5	1	21.5	no
t _{PHL}	SKOLK	Q _H '			9.2	16.5	1	21.5	ns
t _{PHL}	SRCLR	Q _{H'}	C _L = 50 pF		9	16.3	1	20.2	ns
t _{PZH}	- OE	Q _A –Q _H	C _L = 50 pF		7.8	15	1	20	ns
t _{PZL}	OE	QA-QH			9.6	15	1	20	115
t _{PHZ}	- OE	0 0	C = 50 pF		8.1	15.7	1	19.2	no
t _{PLZ}	OE .	Q _A –Q _H	C _L = 50 pF		9.3	15.7	1	19.2	ns

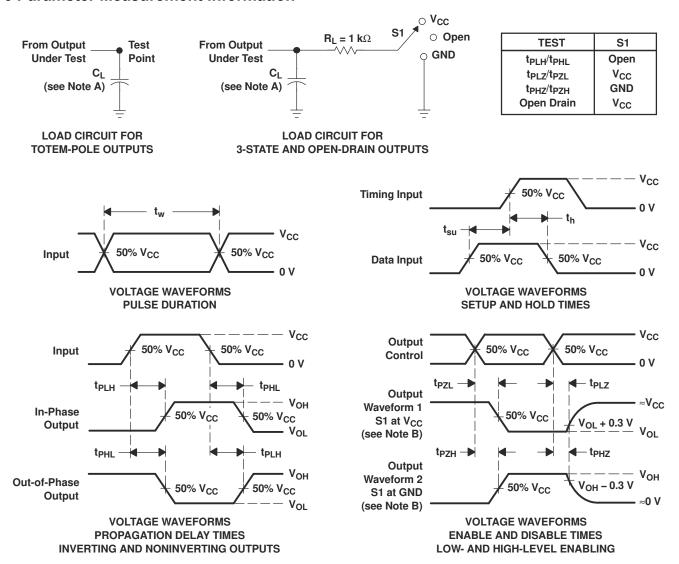
5.9 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

 V_{CC} = 5 V ± 0.5 V, over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	TO (OUTPUT)	LOAD	T _A = 25°C			MIN	MAX	UNIT
FARAINETER	(INPUT)		CAPACITANCE	MIN	TYP	MAX	IVIIIV	IVIAA	UNIT
f _{max}			C _L = 50 pF	95	140		75		MHz
t _{PLH}	RCLK	Q _A –Q _H	$C_1 = 50 \text{ pF}$		5.6	9.4	1	13.5	ns
t _{PHL}	RCLK	QA-QH	CL = 30 pr		5.6	9.4	1	13.5	115
t _{PLH}	SDCLK	SRCLK Qu	C _L = 50 pF		6.4	10.2	1	14.4	l ns
t _{PHL}	SKOLK	Q _{H'}			6.4	10.2	1	14.4	
t _{PHL}	SRCLR	Q _H '	C _L = 50 pF		6.4	10	1	14.1	ns
t _{PZH}	ŌĒ	0. 0.	C. = 50 pE		5.7	10.6	1	15	ns
t _{PZL}	OE	Q _A –Q _H	C _L = 50 pF		6.8	10.6	1	15	115
t _{PHZ}	ŌĒ	Q _A –Q _H	C ₁ = 50 pF		3.5	10.3	1	14	ns
t _{PLZ}	OL .	Q _A −Q _H	OL - 30 pi		3.4	10.3	1	14	113



6 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.

Figure 6-1. Load Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

The SN74AHC595 contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. The storage register has parallel 3-state outputs. Separate clocks are provided for both the shift and storage registers.

The shift register has a direct overriding clear (\overline{SRCLR}) input, serial (SER) input, and a serial output for cascading. When the output-enable (\overline{OE}) input is high, all outputs, except $Q_{H'}$, are in the high-impedance state.

Both the shift-register clock (SRCLK) and storage-register clock (RCLK) are positive-edge triggered. If both clocks are connected together, the shift register always is one clock pulse ahead of the storage register.

7.2 Functional Block Diagram

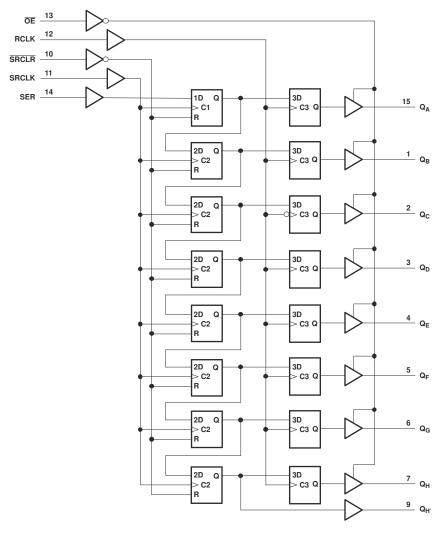


Figure 7-1. Logic Diagram (Positive Logic)



7.3 Device Functional Modes

Table 7-1. Function Table

		INPUTS			FUNCTION				
SER	SRCLK	SRCLR	RCLK	ŌĒ	FUNCTION				
Х	Х	Х	Х	Н	Outputs Q _A –Q _H are disabled.				
X	Χ	Χ	Χ	L	Outputs Q _A –Q _H are enabled.				
X	Χ	L	Χ	Χ	Shift register is cleared.				
L	↑	Н	Х	Х	First stage of the shift register goes low. Other stages store the data of previous stage, respectively.				
Н	↑	Н	Х	Х	First stage of the shift register goes high. Other stages store the data of previous stage, respectively.				
Х	Х	Х	1	Х	Shift-register data is stored into the storage register.				



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

8.2 Layout

8.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused (for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used). Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

8.2.2 Layout Example

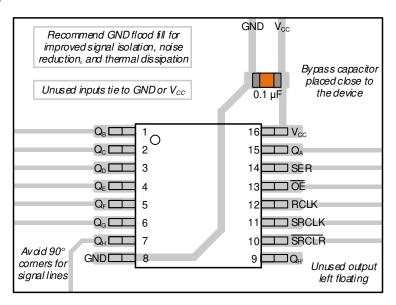


Figure 8-1. Example Layout for the SN74AHC595-Q1



9 Device and Documentation Support

9.1 Document Support (Analog)

9.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 9-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74AHC595-Q1	Click here	Click here	Click here	Click here	Click here	

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (March 2024) to Revision E (April 2024)

Page

Changes from Revision C (November 2023) to Revision D (March 2024)

Added BQB package to Package Information table, Pin Configuration and Functions section, and Thermal

Product Folder Links: SN74AHC595-Q1



11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC595QPWRQ1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA595Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74AHC595-Q1:

PACKAGE OPTION ADDENDUM

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Catalog : SN74AHC595

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC595QPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC595QPWRQ1	TSSOP	PW	16	2000	356.0	356.0	35.0



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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